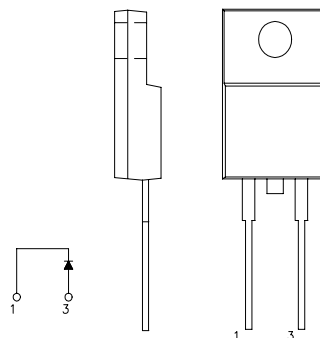


SBD Type : FSH10A15

OUTLINE DRAWING

構造 : ショトキバリアダイオード (S B D)
Construction: Schottky Barrier Diode

用途 : 高周波整流用
Application : High Frequency Rectification



最大定格 / Maximum Ratings

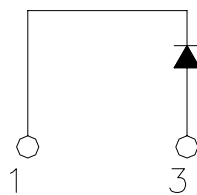
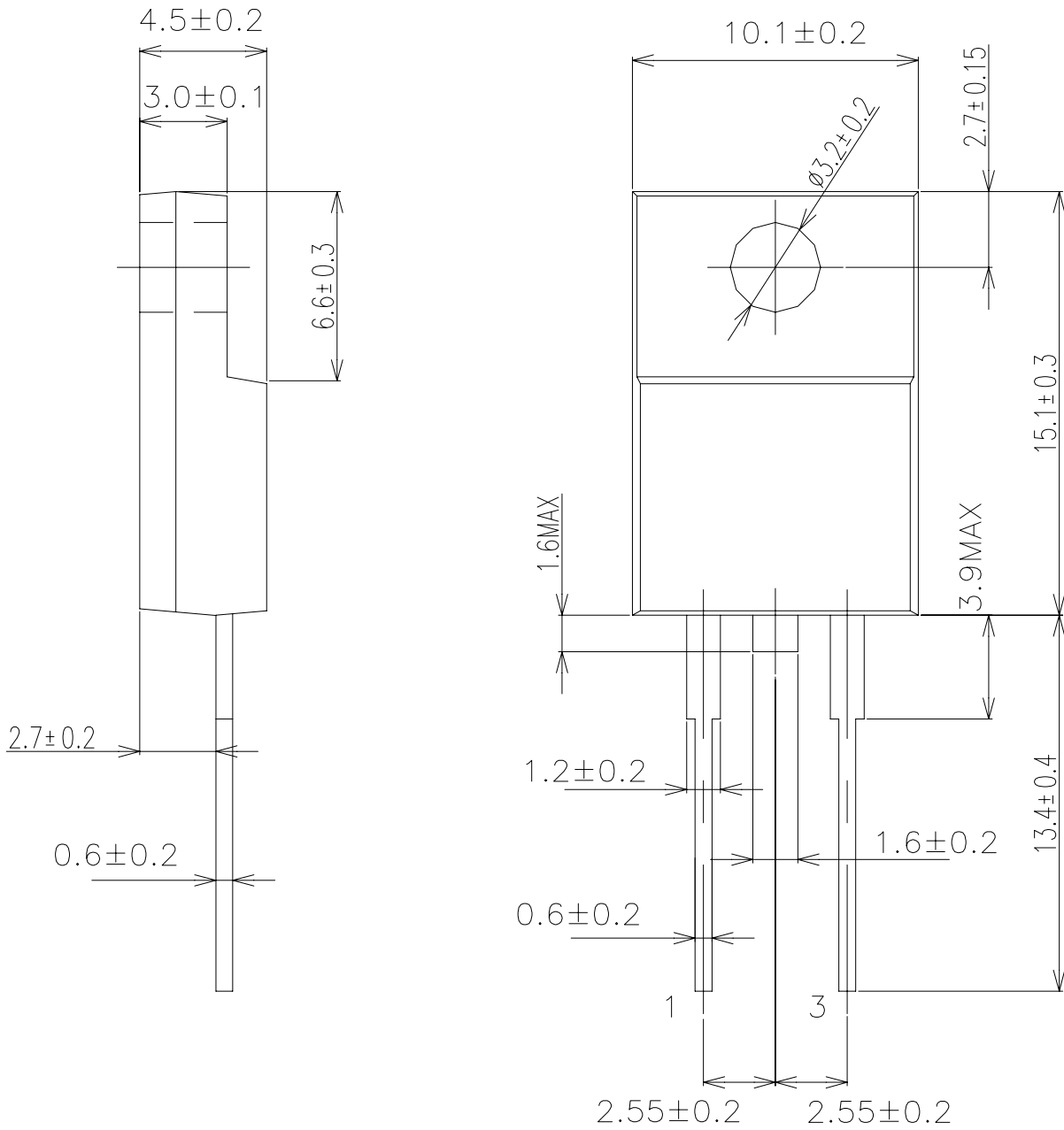
Approx Net Weight:1.7g

Rating	Symbol	FSH10A15		Unit
くり返しピーク逆電圧 Repetitive Peak Reverse Voltage	V_{RRM}	150		V
平均整流電流 Average Rectified Output Current	I_O	10	Tc=120 50 Hz、正弦半波通電抵抗負荷 Half Sine Wave, Resistive Load	A
実効順電流 RMS Forward Current	$I_{F(RMS)}$	15.7		A
サージ順電流 Surge Forward Current	I_{FSM}	180	50 Hz 正弦半波, 1サイクル, 非くり返し Half Sine Wave, 1cycle, Non-repetitive	A
動作接合温度範囲 Operating Junction Temperature Range	Tjw	- 40 ~ + 150		
保存温度範囲 Storage Temperature Range	Tstg	- 40 ~ + 150		
締付けトルク Mounting torque	Ftor	(推奨値 recommended torque=0.5)		N·m

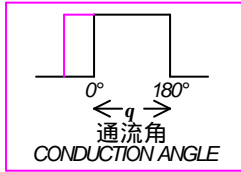
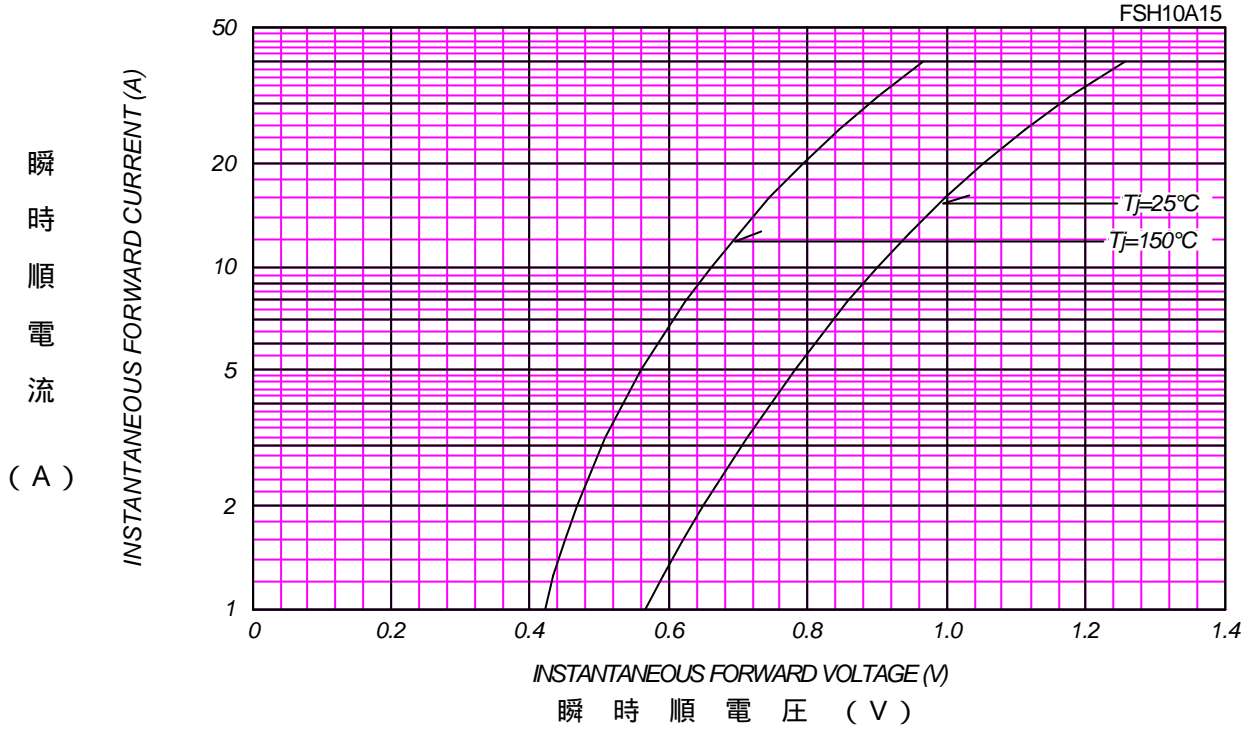
電氣的・熱的特性 / Electrical · Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
ピーク逆電流 Peak Reverse Current	I_{RM}	Tj= 25 , $V_{RM}= V_{RRM}$	-	-	1	mA
ピーク順電圧 Peak Forward Voltage	V_{FM}	Tj= 25 , $I_{FM}= 10 A$	-	-	0.9	V
熱抵抗 Thermal Resistance	接合部・ケース間 Junction to Case	Rth(j-c) Junction to Case	-	-	3	/W
	ケース・フィン間 Case to Fin	Rth(c-f) Case to Fin	-	-	1.5	/W

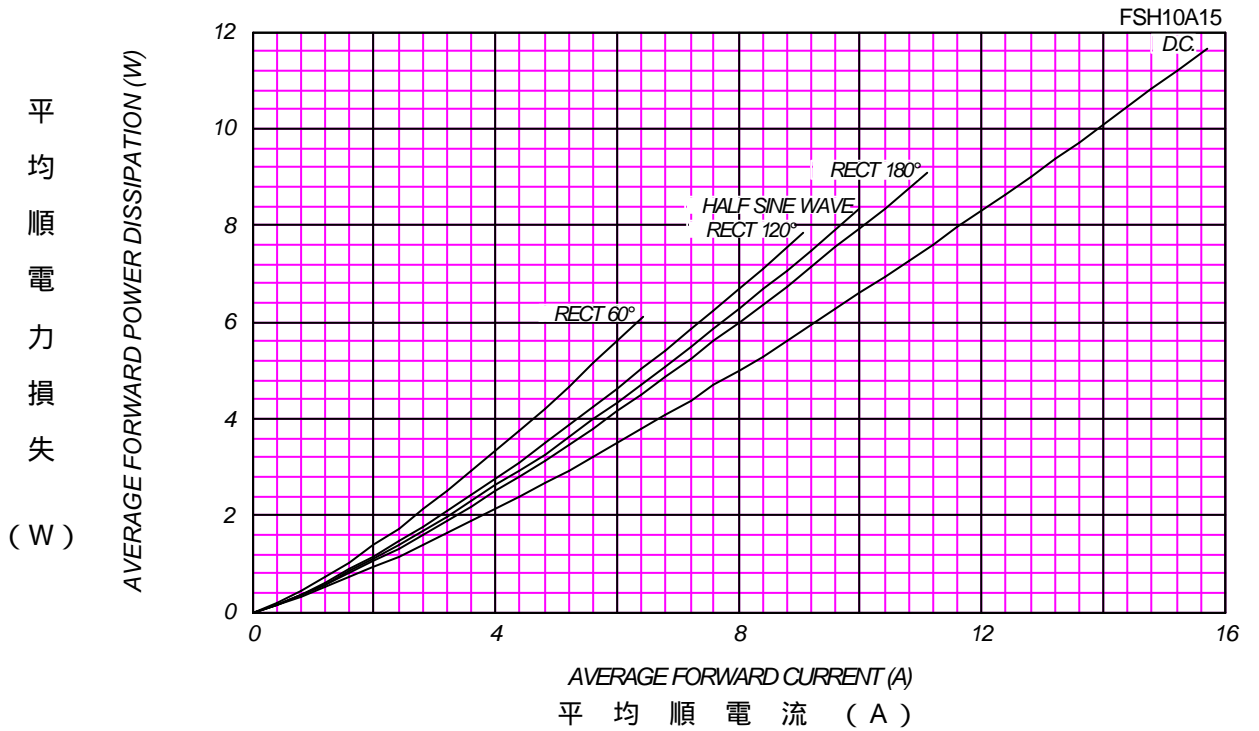
F S H_A_外形図 (mm)



順電壓特性
FORWARD CURRENT VS. VOLTAGE

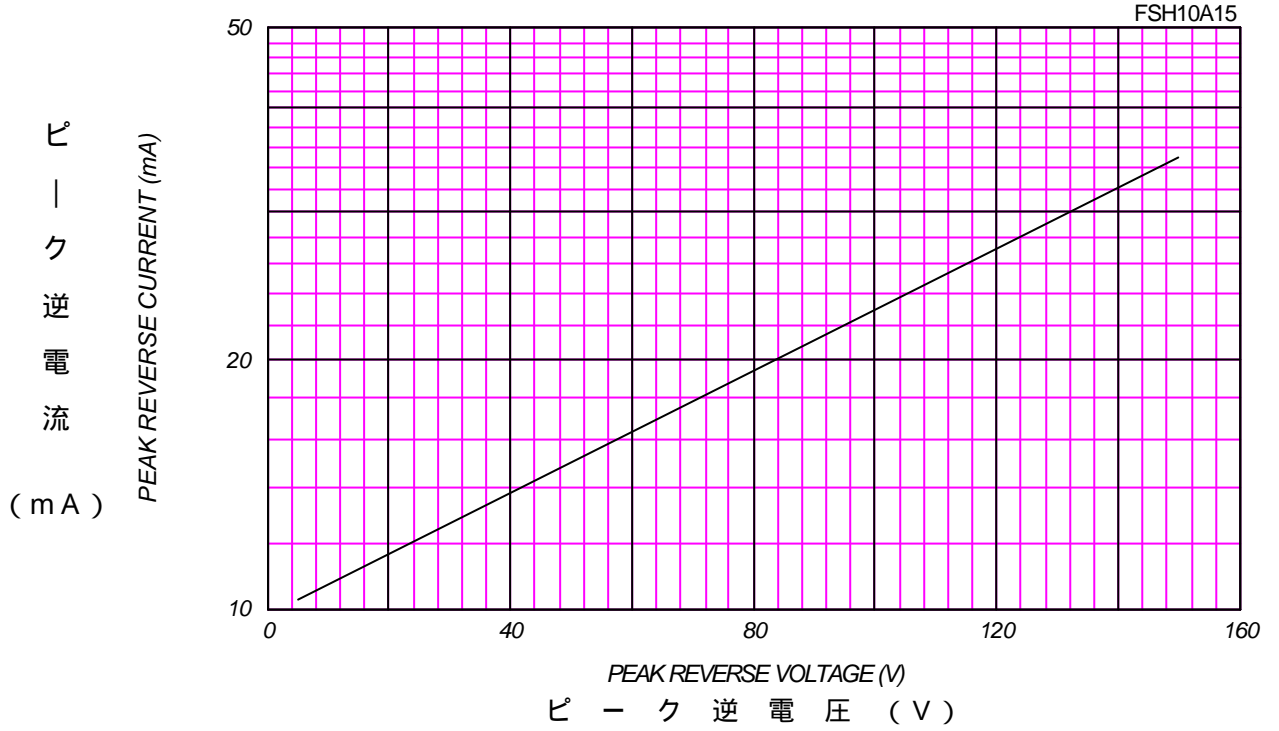


平均順電力損失特性
AVERAGE FORWARD POWER DISSIPATION

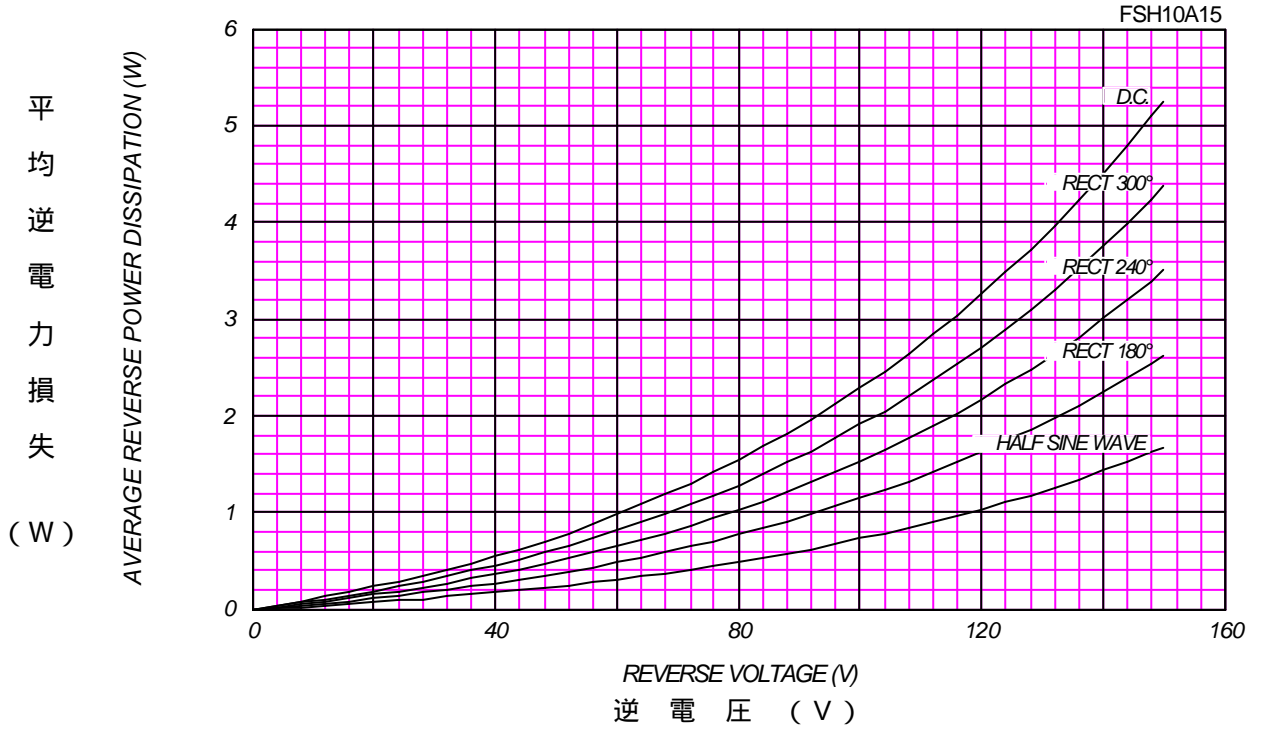


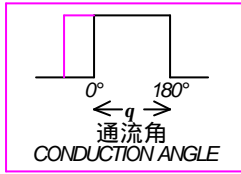
ピーク逆電流 - ピーク逆電圧特性
 PEAK REVERSE CURRENT VS. PEAK REVERSE VOLTAGE

T_j = 150 °C



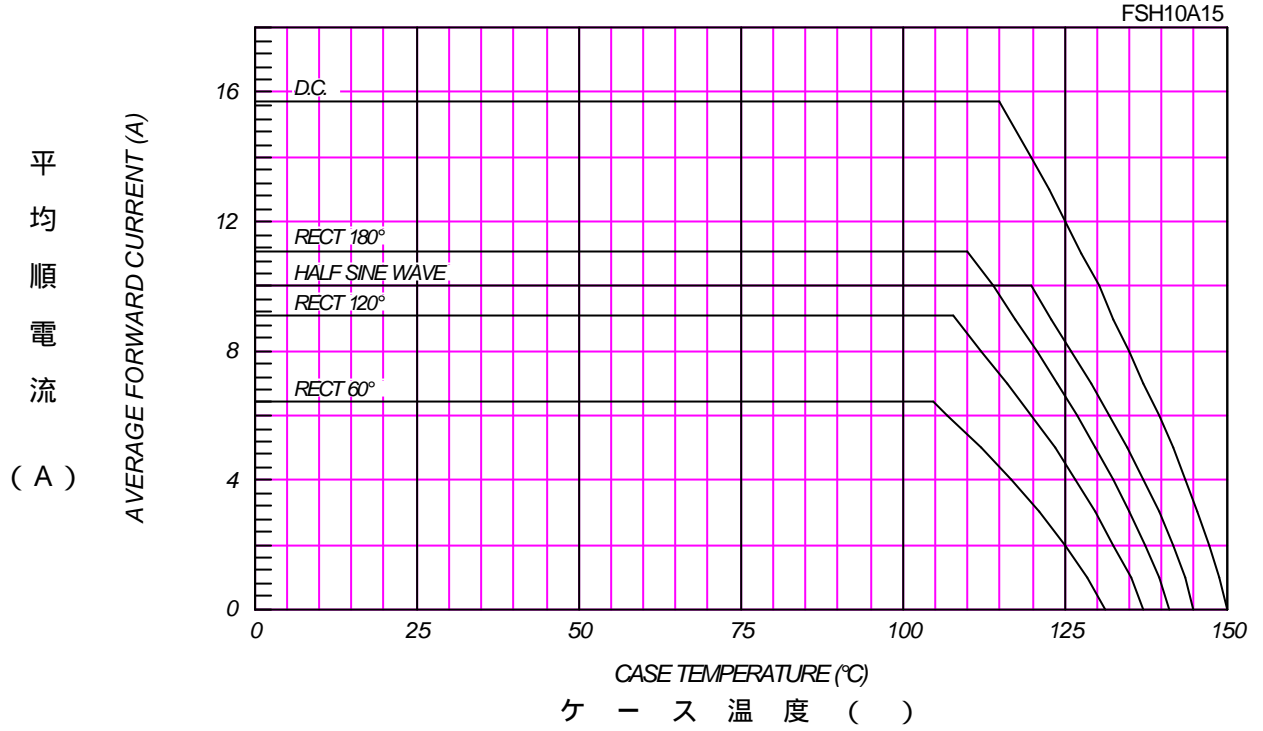
平均逆電力損失
 AVERAGE REVERSE POWER DISSIPATION





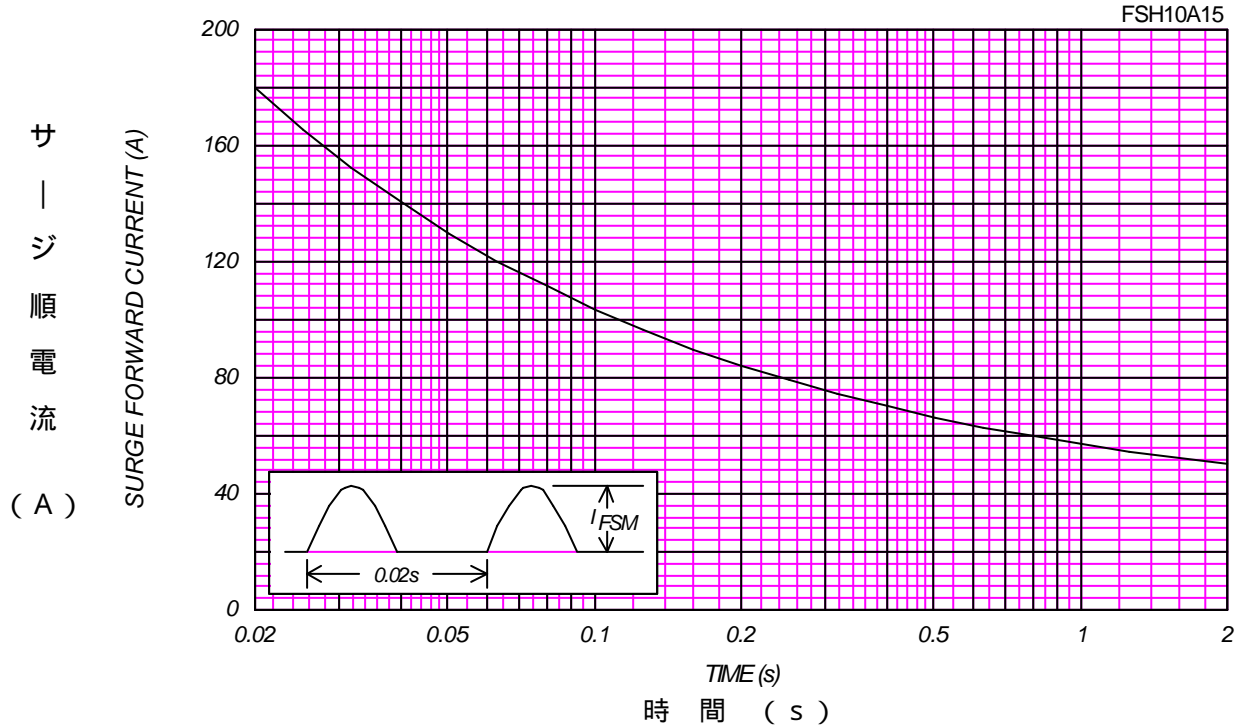
平均順電流 - ケース温度定格
AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

$V_{RM}=150V$



サージ順電流定格
SURGE CURRENT RATINGS

f=50Hz, Sine Wave, Non-Repetitive, No Load



接合容量特性
JUNCTION CAPACITANCE VS. REVERSE VOLTAGE

$T_j=25^\circ\text{C}$, $V_m=20\text{mV}_{\text{RMS}}$, $f=100\text{kHz}$, Typical Value

FSH10A15

